



40V NPN LOW VCESAT TRANSISTOR IN PowerDI3333-8

Features

- BV_{CEO} > 40V
- Small Form Factor Thermally Efficient Package. **Enables Higher Density End Products**
- I_C = 2A High Continuous Collector Current
- I_{CM} = 3A Peak Pulse Current
- Low Saturation Voltage V_{CE(sat)} < 320mV @ 1A
- Complementary PNP Type: DXTP22040DFGQ
- Wettable Flank for Improved Optical Inspection
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DXTN22040DFGQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

Mechanical Data

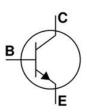
- Case: PowerDI®3333-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.03 grams (Approximate)

Applications

- DC to DC Conversion
- Supply Line Switching
- Low Drop Out Regulation
- LCD Backlighting

PowerDI3333-8 (SWP) (Type UX)





Device Symbol



Top View

Bottom View

Ordering Information (Note 4)

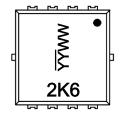
Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
DXTN22040DFGQ-7	Automotive	2K6	7	12	2,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

PowerDI3333-8 (SWP) (Type UX)



2K6 = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 21 = 2021) WW = Week Code (01 to 53)



Absolute Maximum Ratings (@ $T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	Vсво	50	V
Collector-Emitter Voltage	V _{CEO}	40	V
Emitter-Base Voltage	V _{EBO}	7	V
Continuous Collector Current	Ic	2	Α
Peak Pulse Collector Current	I _{CM}	3	Α
Continuous Base Current	lB	100	mA
Peak Pulse Base Current	Івм	200	mA

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Discipation	(Note 5)	De	1.1	W
Power Dissipation	(Note 6)	P _D	2.3	W
Thermal Resistance, Junction to Ambient	(Note 5)	D	113	°C/W
Thermal nesistance, Junction to Ambient	(Note 6)	Reja	55	°C/W
Thermal Resistance, Junction to Leads (Note	R _{0JL}	7.4	°C/W	
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C	

ESD Ratings (Note 8)

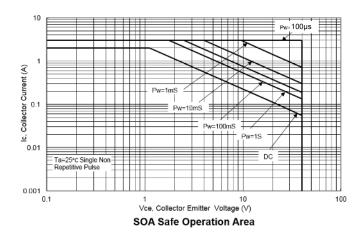
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge – Human Body Model	ESD HBM	4,000	V	3A
Charge Device Model	CDM	1,000	V	C5

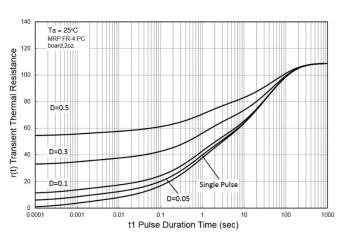
Notes:

- 5. For a device mounted with the collector tab on MRP FR4-PCB; device is measured under still air conditions whilst operating in a steady-state.
- 6. Same as Note 5, except the device is mounted on 25mm x 25mm 2oz copper.
- 7. Thermal resistance from junction to solder-point (at the collector tab).
- 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

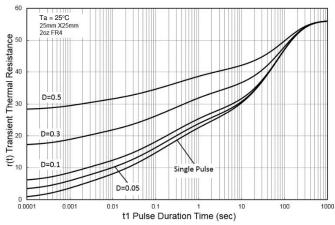


Thermal Characteristics and Derating Information

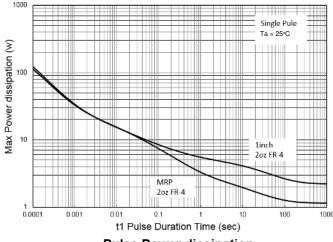




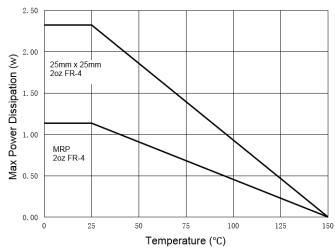
Transient Thermal Resistance



Transient Thermal Resistance



Pulse Power dissipation



Derating Curve

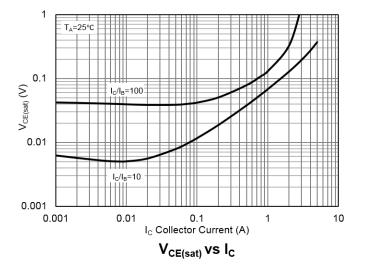


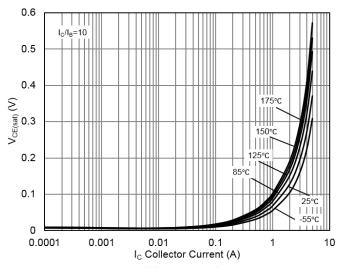
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

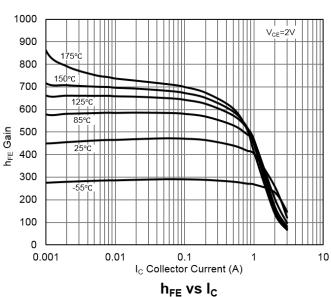
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	50	171	_	V	$I_C = 100\mu A$
Collector-Emitter Breakdown Voltage (Note 9)	BVceo	40	54	_	V	Ic = 10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	7	8.1	_	V	I _E = 100μA
Collector-Base Cut-Off Current	Ісво		1	50	nA	V _{CB} = 40V
Collector-base out-on ounent			0.01	10	μΑ	$V_{CB} = 40V, T_A = +150^{\circ}C$
Emitter-Base Cut-Off Current	I _{EBO}	-	1	20	nA	$V_{EB} = 6V$
Collector-Emitter Cut-Off Current	ICES	l	1	50	nA	$V_{CE} = 40V$, $V_{BE} = 0V$
Static Forward Current Transfer Ratio (Note 9)	hFE	300 300 200 140	464 468 445 377	900 — —	_	IC = 1mA, VCE = 2V IC = 500mA, VCE = 2V IC = 1A, VCE = 2V IC = 2A, VCE = 2V
Collector-Emitter Saturation Voltage (Note 9)	VCE(sat)		43 38 68 126 187	80 120 220 350 600	mV	Ic = 100mA, I _B = 1mA Ic = 500mA, I _B = 50mA Ic = 1A, I _B = 100mA Ic = 2A, I _B = 200mA Ic = 3A, I _B = 300mA
Base-Emitter Saturation Voltage (Note 9)	V _{BE(sat)}	l	0.9	1.1	V	Ic = 1A, I _B = 100mA
Base-Emitter Turn-On Voltage (Note 9)	V _{BE(on)}	1	0.74	1	V	Ic = 1A, VcE = 5V
Input Capacitance	Cibo		161	_	pF	$V_{EB} = 0.5V$, $f = 1MHz$
Output Capacitance	Cobo		11	_	pF	V _{CB} = 10V, f = 1MHz
Transition Frequency	fτ	1	198	_	MHz	I _C = 50mA, V _{CE} = 10V f = 100MHz
	tdelay	_	7.9	_	ns	
Switching Time	trise		2.9	_	ns	Ic = 1A, Vcc = 10V,
Switching Time	tstorage	-	673	_	ns	I _{B1} = -I _{B2} = 100mA
	tfall		26.8	_	ns	

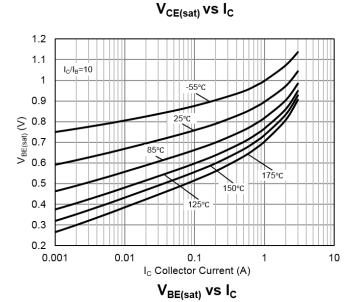
Note: 9. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.

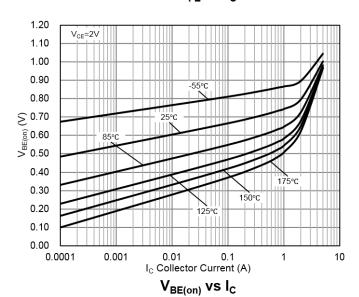


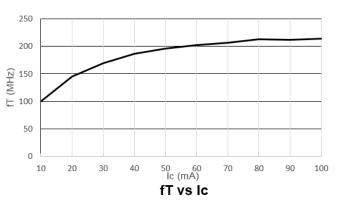










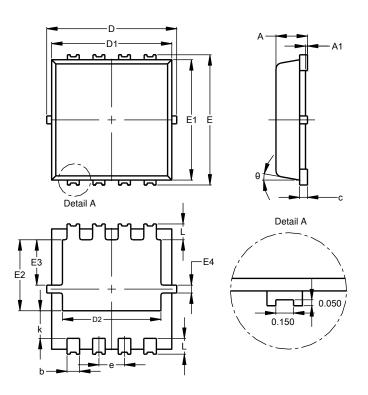




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8 (SWP) (Type UX)

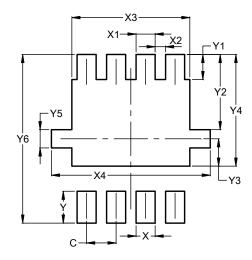


PowerDI3333-8 (SWP)					
(Type UX) ´					
Dim	Min	Max	Тур		
Α	0.75	0.85	0.80		
A 1	0.00	0.05			
b	0.25	0.40	0.32		
С	0.10	0.25	0.15		
D	3.20	3.40	3.30		
D1	2.95	3.15	3.05		
D2	2.30	2.70	2.50		
Е	3.20	3.40	3.30		
E1	2.95	3.15	3.05		
E2	1.60	2.00	1.80		
E3	0.95	1.35	1.15		
E4	0.10	0.30	0.20		
е	1	-	0.65		
k	0.50	0.90	0.70		
L	0.30	0.50	0.40		
θ	0°	12°	10°		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8 (SWP) (Type UX)



Dimensions	Value (in mm)
С	0.650
X	0.420
X1	0.420
X2	0.230
Х3	2.600
X4	3.500
Υ	0.700
Y1	0.550
Y2	1.650
Y3	0.600
Y4	2.450
Y5	0.400
Y6	3.700



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